

Light Engineering in New Materials

How material science can help in realizing new
efficient incoherent and coherent light sources

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Outline

- ▶ A little bit of history
- ▶ Band-gap engineering
- ▶ Epitaxial growth
- ▶ Chemical synthesis
- ▶ Perovskites
- ▶ A look to the future

A little bit of history: 150 years from the Mendeleev Table

The semiconductor tree



The Mendeleeev table is the tree
principal root

										VIIIA	
										1	He
										2	Ne
										3	Ar
										4	Kr
										5	Xe
										6	Rn
										7	
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										100	

The recognition of material science relevance

The nanostructures and the superconductors

The Nobel Prize in Physics 1973



Photo from the Nobel Foundation archive.

Leo Esaki

Prize share: 1/4



Photo from the Nobel Foundation archive.

Ivar Giaever

Prize share: 1/4



Photo from the Nobel Foundation archive.

Brian David Josephson

Prize share: 1/2

The Nobel Prize in Physics 1973 was divided, one half jointly to Leo Esaki and Ivar Giaever "for their experimental discoveries regarding tunneling phenomena in semiconductors and superconductors, respectively" and the other half to Brian David Josephson "for his theoretical predictions of the properties of a supercurrent through a tunnel barrier, in particular those phenomena which are generally known as the Josephson effects."

Heterostructures and integrated circuit



The Nobel Prize in Physics 2000

"for basic work on information and communication technology"

"for developing semiconductor heterostructures used in high-speed- and opto-electronics"

"for his part in the invention of the integrated circuit"



Zhores I. Alferov

🕒 1/4 of the prize

Russia

A.F. Ioffe Physico-
Technical Institute
St. Petersburg, Russia

b. 1930



Herbert Kroemer

🕒 1/4 of the prize

Federal Republic of
Germany

University of California
Santa Barbara, CA, USA

b. 1928



Jack S. Kilby

🕒 1/2 of the prize

USA

Texas Instruments
Dallas, TX, USA

b. 1923
d. 2005

The CCD



The Nobel Prize in Physics 2009

"for groundbreaking achievements concerning the transmission of light in fibers for optical communication"

"for the invention of an imaging semiconductor circuit – the CCD sensor"



Photo: U. Montan

Charles K. Kao

🕒 1/2 of the prize

Standard
Telecommunication
Laboratories
Harlow, United Kingdom;
Chinese University of
Hong Kong
Hong Kong, China



Photo: U. Montan

Willard S. Boyle

🕒 1/4 of the prize

Bell Laboratories
Murray Hill, NJ, USA



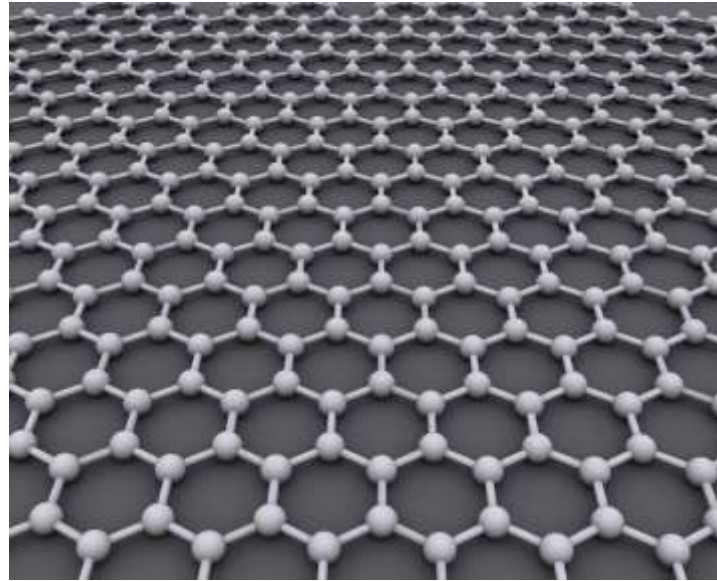
Photo: U. Montan

George E. Smith

🕒 1/4 of the prize

Bell Laboratories
Murray Hill, NJ, USA

The Graphene: the perfect lattice



The Nobel Prize in Physics 2010

Andre Geim and Konstantin Novoselov

"for groundbreaking experiments regarding the two-dimensional material graphene"



The blue/white laser diodes

The Nobel Prize in Physics 2014



Photo: A. Mahmoud
Isamu Akasaki
Prize share: 1/3

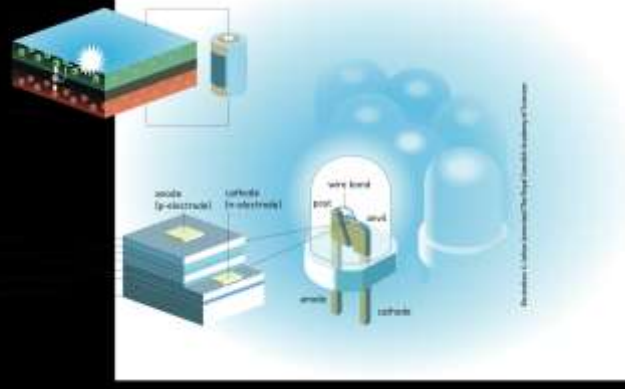


Photo: A. Mahmoud
Hiroshi Amano
Prize share: 1/3



Photo: A. Mahmoud
Shuji Nakamura
Prize share: 1/3

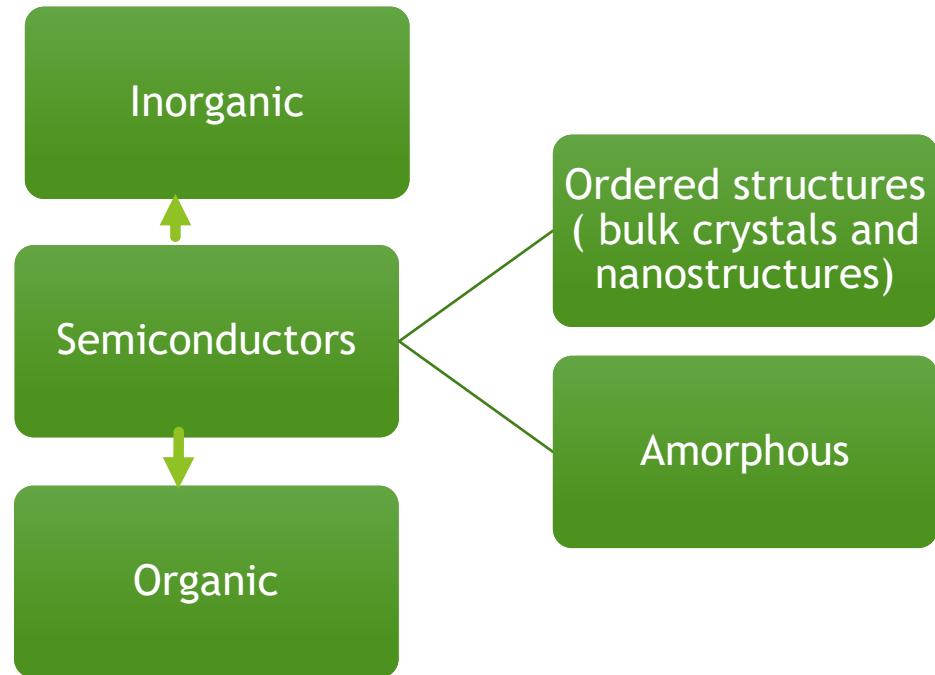
The Nobel Prize in Physics 2014 was awarded jointly to Isamu Akasaki, Hiroshi Amano and Shuji Nakamura *"for the invention of efficient blue light-emitting diodes which has enabled bright and energy-saving white light sources"*.



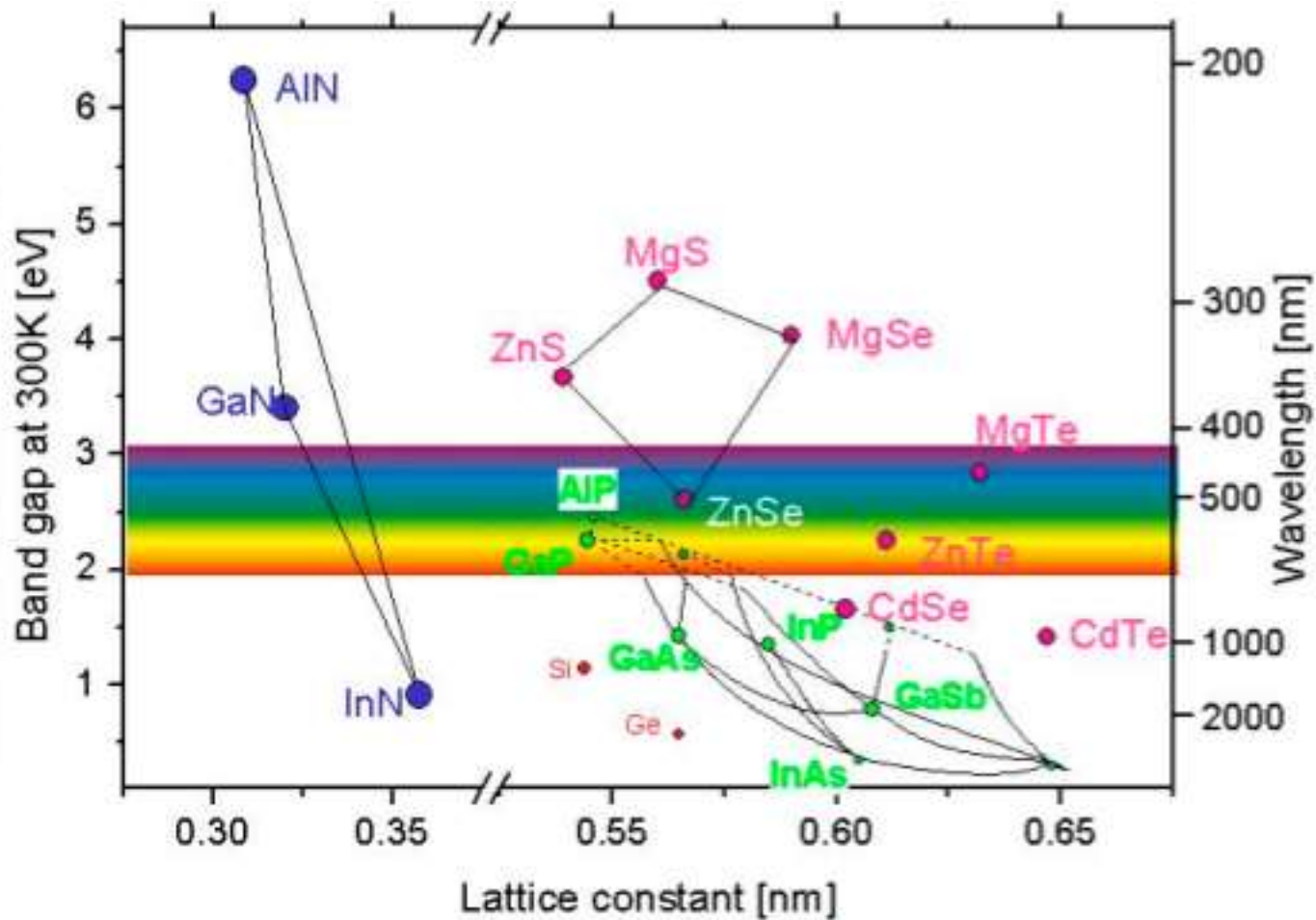
Lights of Tuscany 2019

April 15, 2019

The materials for opto-devices



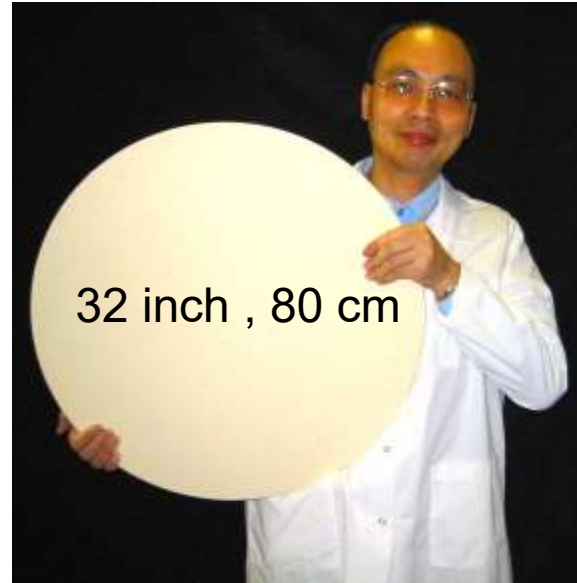
The Rosetta Stone of Semiconductors



The King of Semiconductors for electronics: Silicon



Lights of Tuscany 2019

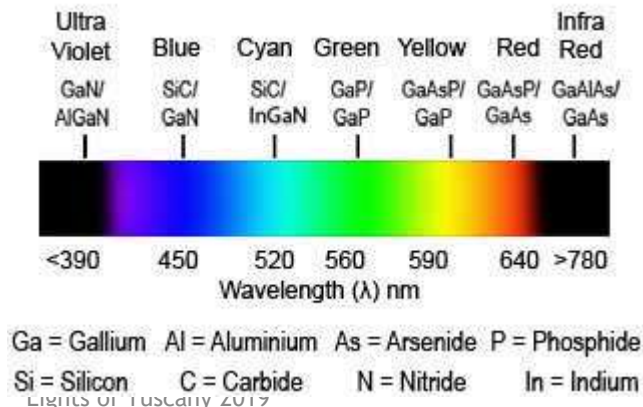


Unfortunately Si is very bad for light emitters being an indirect band-gap semiconductor, so it is hard to have electrons and holes recombining in a radiative way !

The Kings of Semiconductors for light emitters : III-V and III-Nitrides

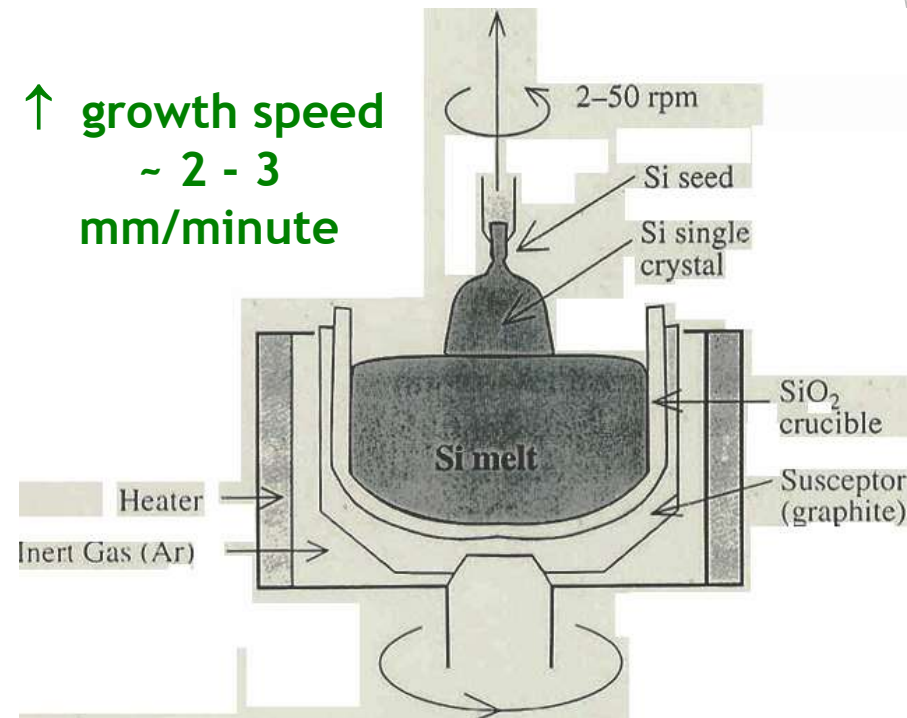
In,Ga,Al Arsenide and Nitride Alloys with a band gap value ranging from 0.8 to 4 eV

We can realize a device emitting light from 1.55 μm (perfect for telecomm) and 300 nm (perfect for UV- lithography and blue-rays, UV curing, etc.). White LEDs are realized using nitride alloys.

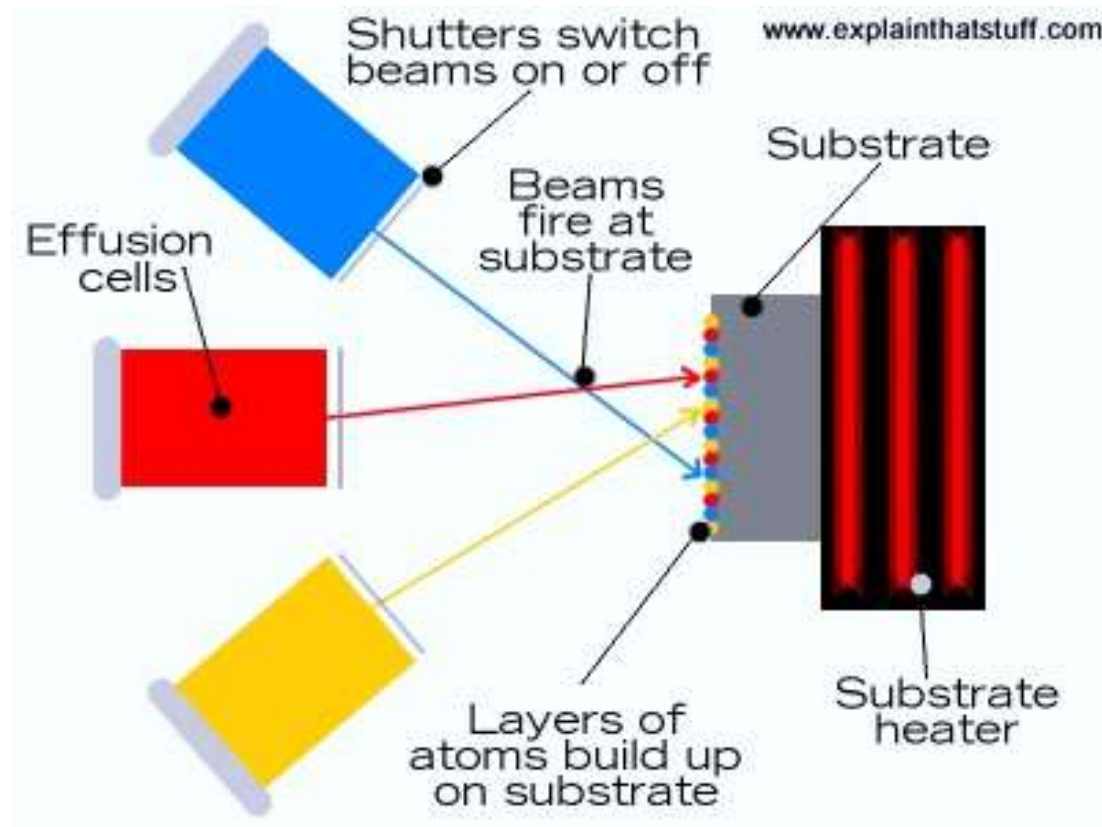


How materials are realized?

- ▶ Czochralski growth (1916): very fast for big crystals : O and C common contaminants
- ▶ Epitaxial growth developed in late 1960s in Bell Labs

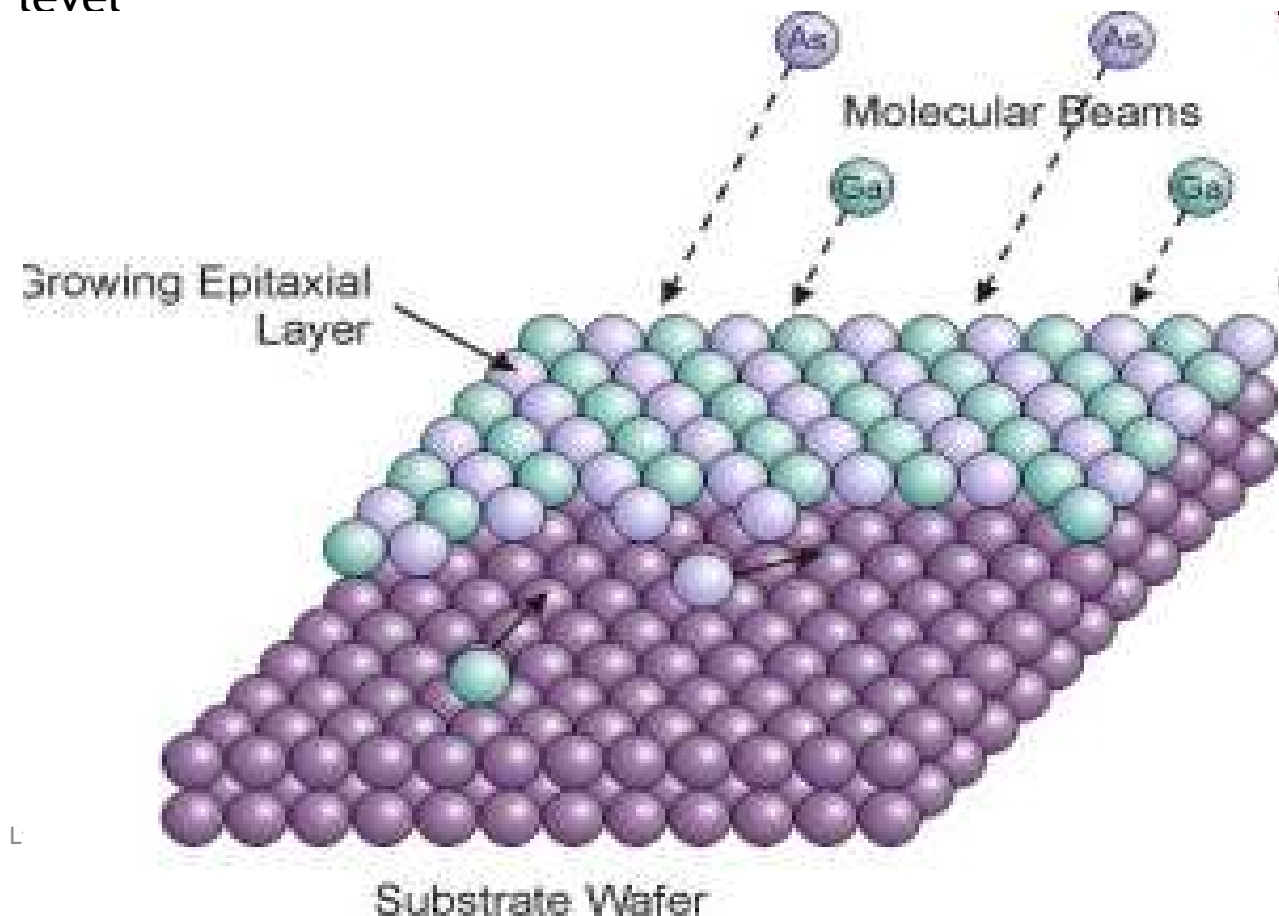


Molecular Beam Epitaxy



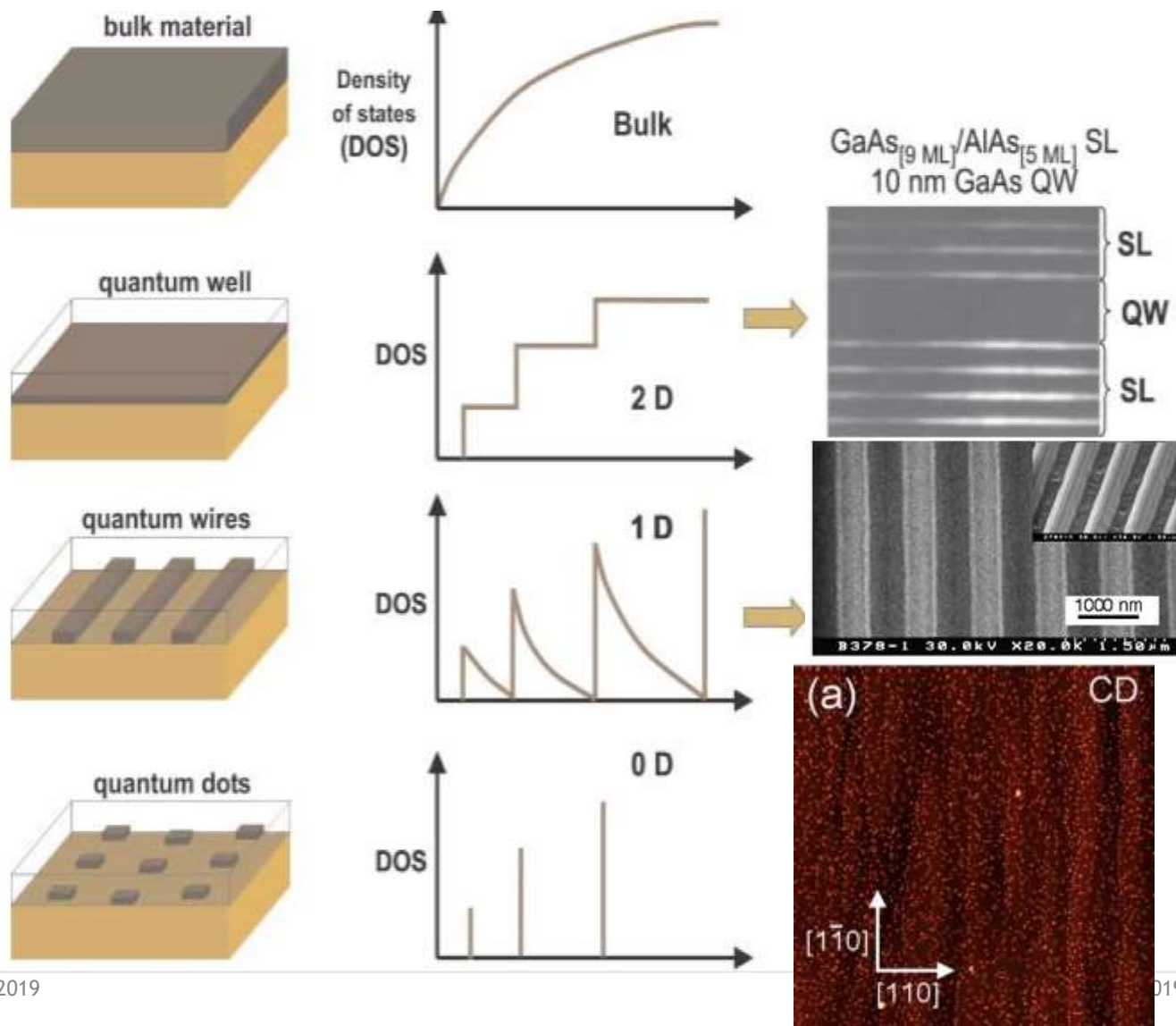
Epitaxy can be by Molecular Beam, Chemical Vapour, Liquid Phase

Epitaxy means in “growth in an ordered way”: epitaxial growth is therefore a growth with an high control of the deposition, at the atomic level



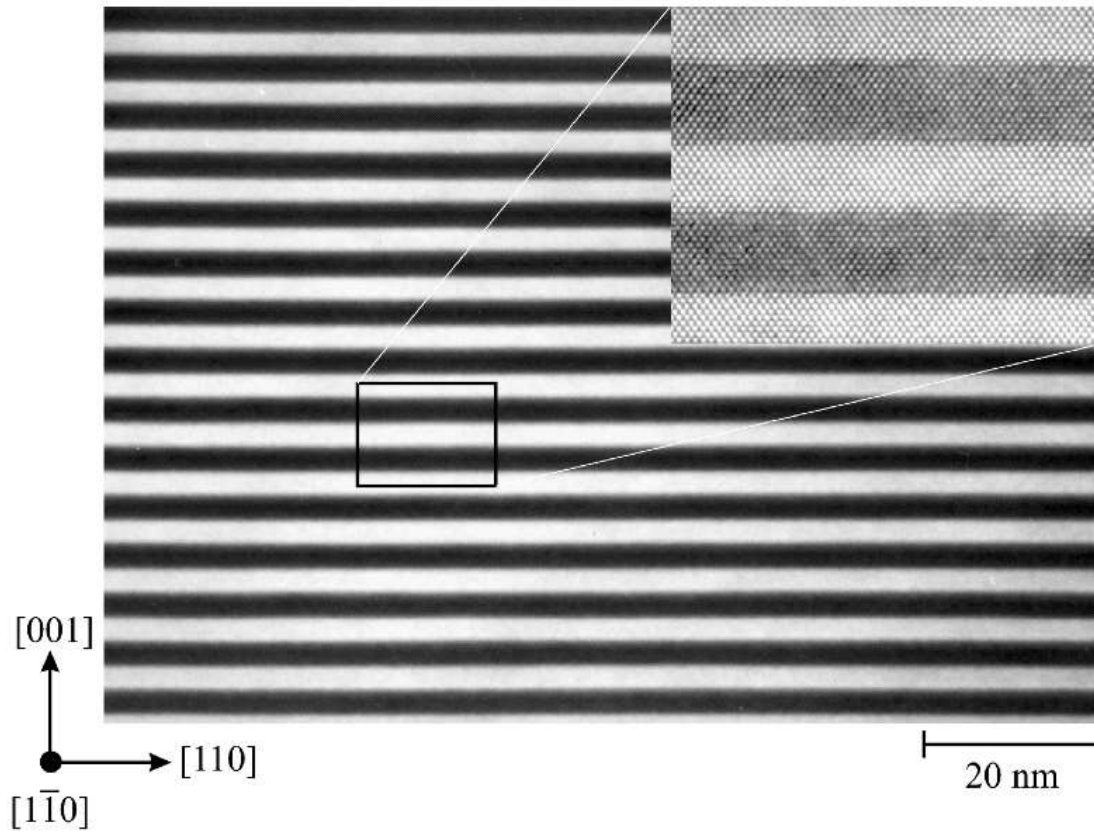
It requires same crystallographic lattice and “same” lattice constant to avoid extended defects which are detrimental for the device operation

But Nature can help: Self-assembled growth

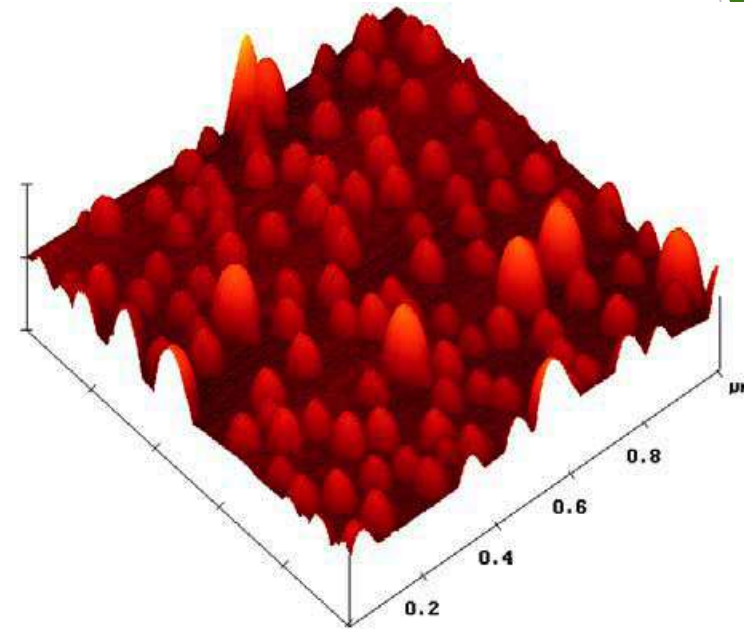


Some results

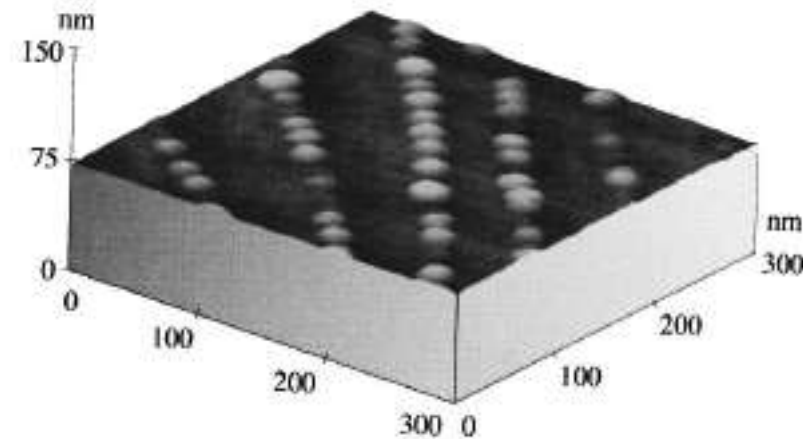
A superlattice



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Quantum dots



What's the meaning?

We can modify the electronic properties (energy, band dispersion, band gap...) at the nanoscale (few Angstrom up to tens of nm)

Quantum effects dominate and we can tailor the material properties the way we prefer

So very nice results but.....
Highly expensive techniques

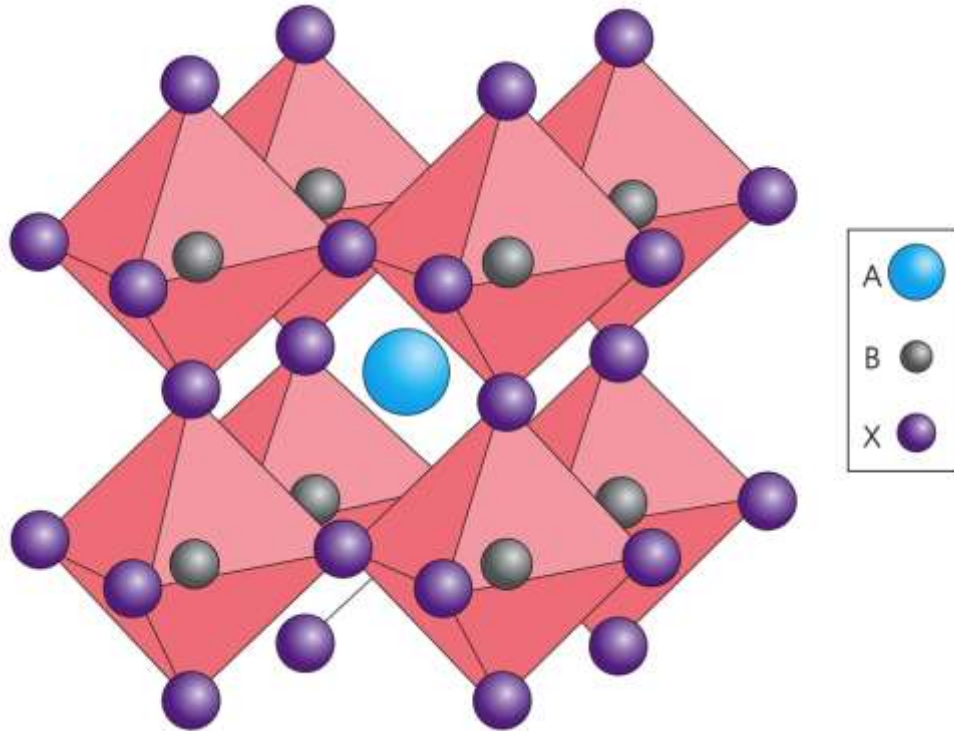
As alternative:

Chemical synthesis

Advantages of chemical synthesis

- ▶ Low cost synthesis and processing
- ▶ High tunability of band-gap
- ▶ Easier integration in photonic structures

The promising class of materials: Perovskites



Same class of material
as CaTiO_3

A: Ca^{2+}

B: Ti^{4+}

X: O^-

Depending on A, they can be
hybrid with organic cation or
fully inorganic

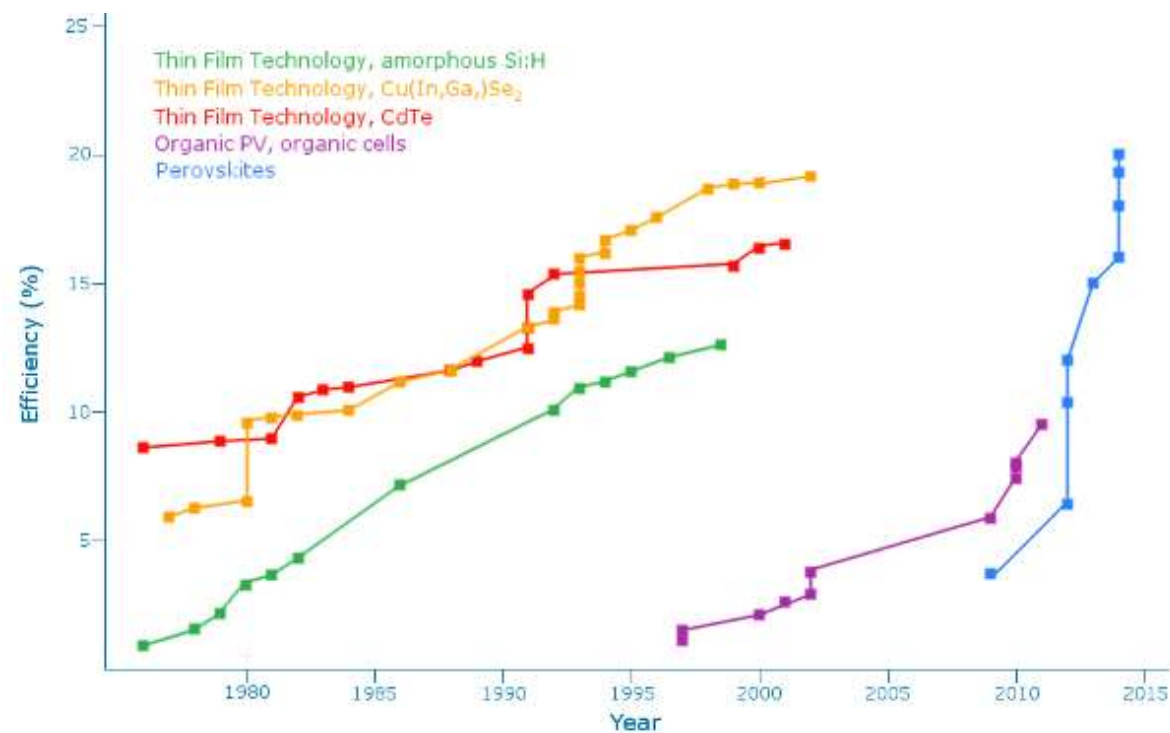
A: CH_3NH_3 , Cs

B: Pb, Sn

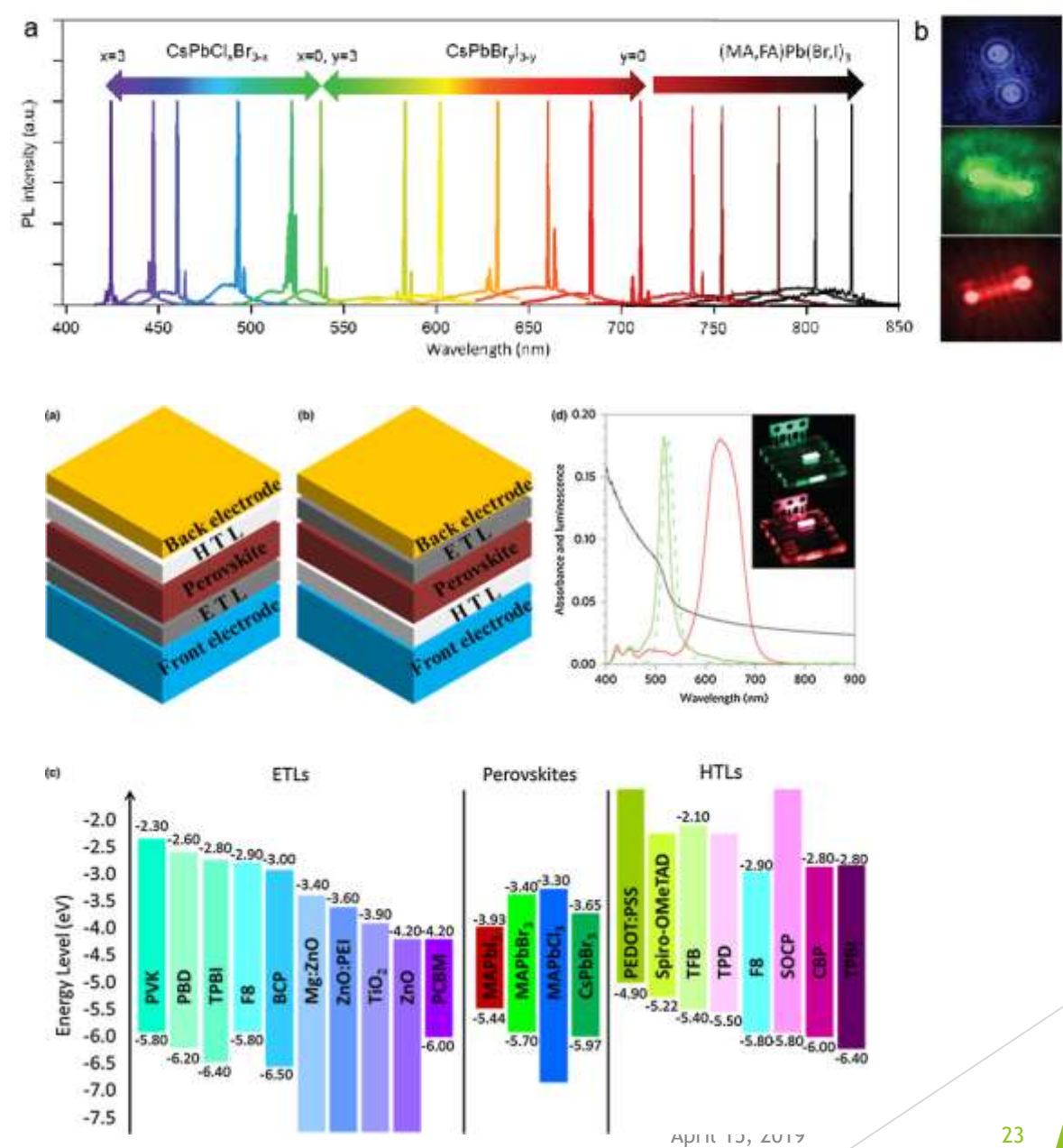
X: Cl, Br, I

Application Fields

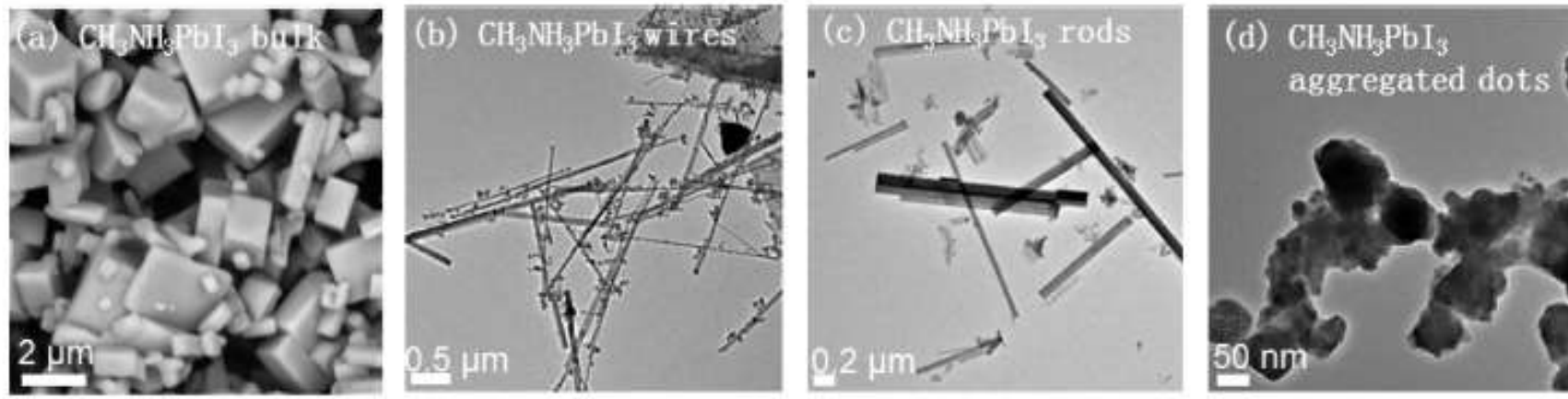
Energy Harvesting



LEDs and Lasers



Different material nanostructuring means different behavior



From bulk to plates, wires, dots

Here in Florence

- Synthesis
- Morphological and structural characterization (XRD, SEM)
- High resolution optical spectroscopy in space and time

Synthesis of nanostructures/thin films

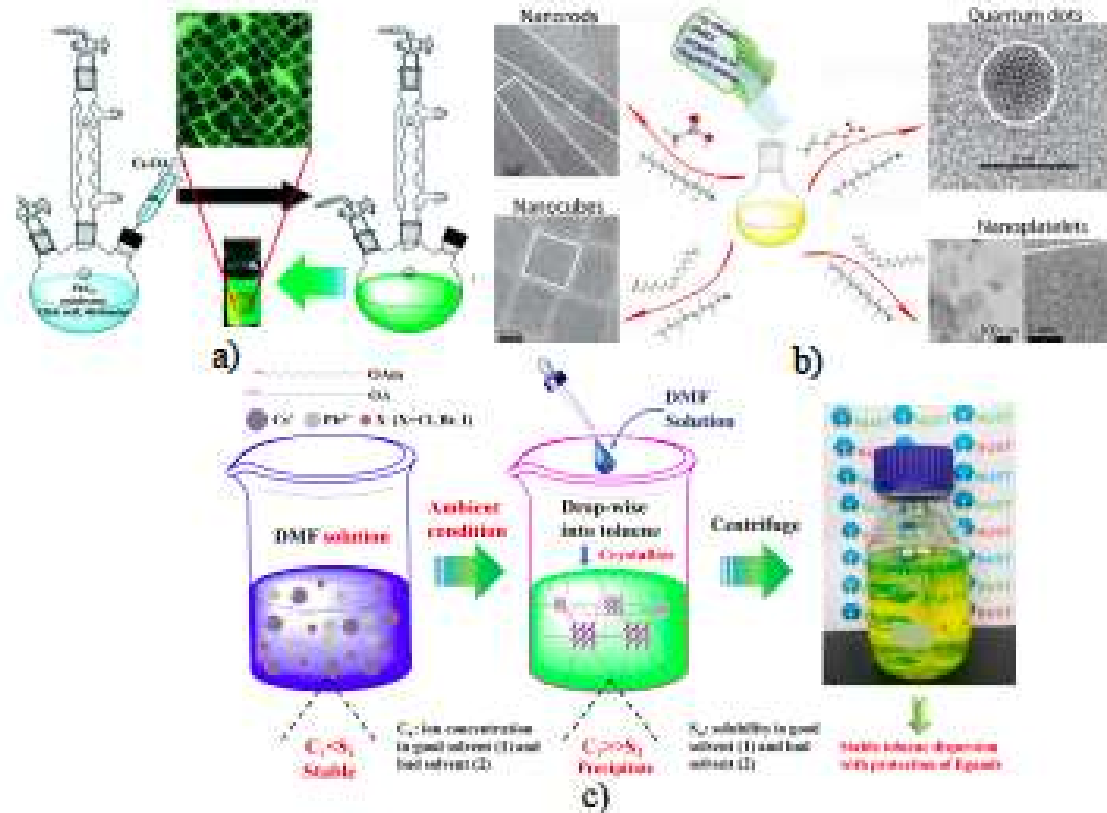
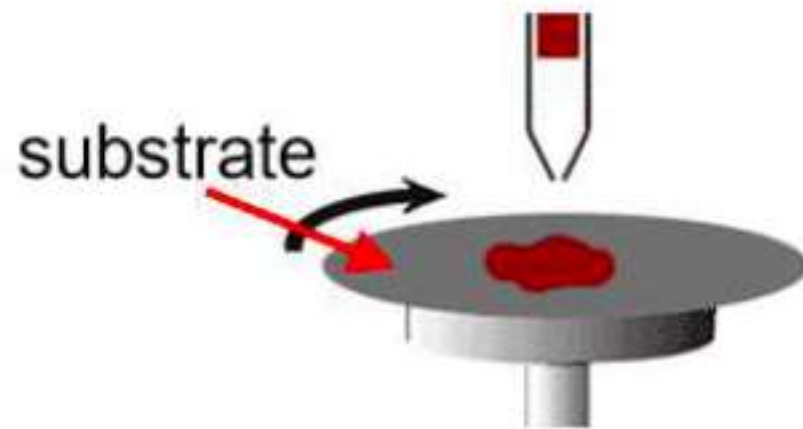


Figure 2.4: Schematic illustration of the most common methods to synthesize CsPbX₃ NCs. a) Hot injection method. The inset shows a corresponding TEM image of the as-produced NCs. b) Room temperature ligand-mediated reprecipitation. By varying the surfactants different structures can be obtained. c) Room temperature supersaturated recrystallization. [56,92,192]

Then precursors are spin-coated on a substrate.....solvent evaporation produces perovskite



For crystals

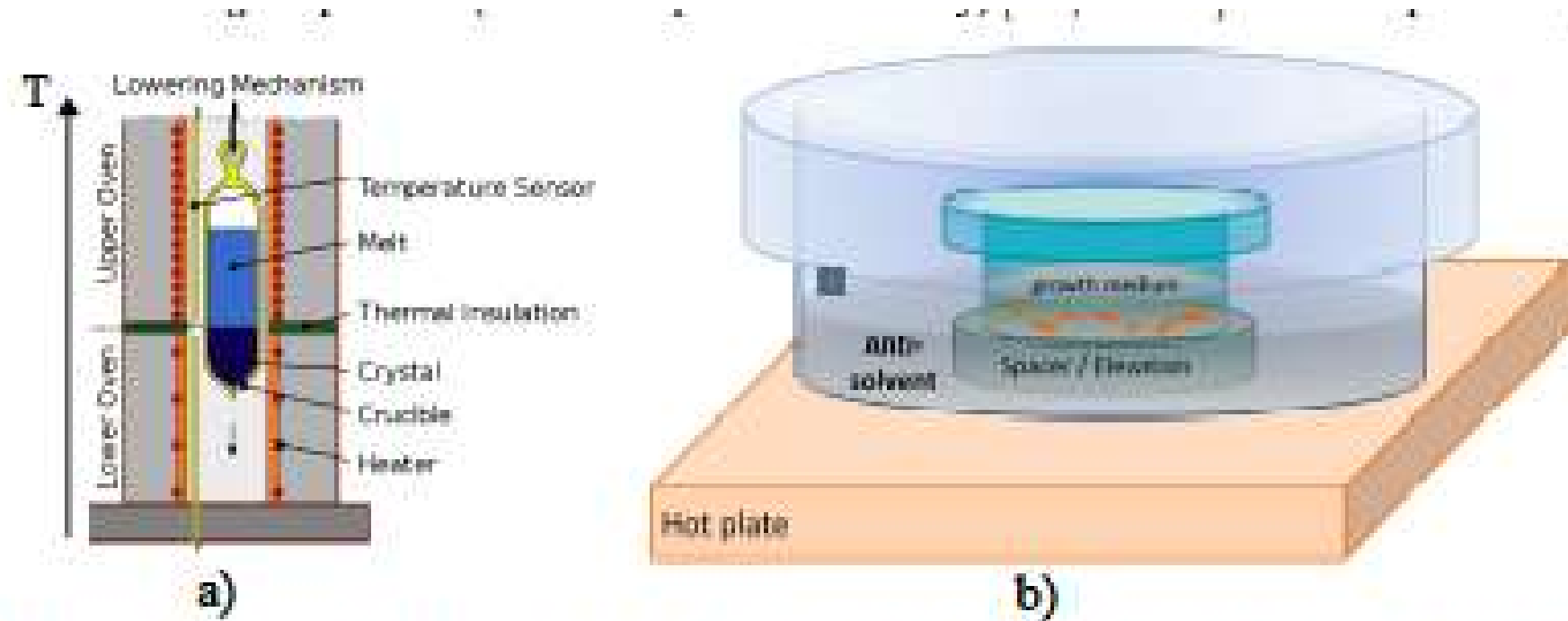
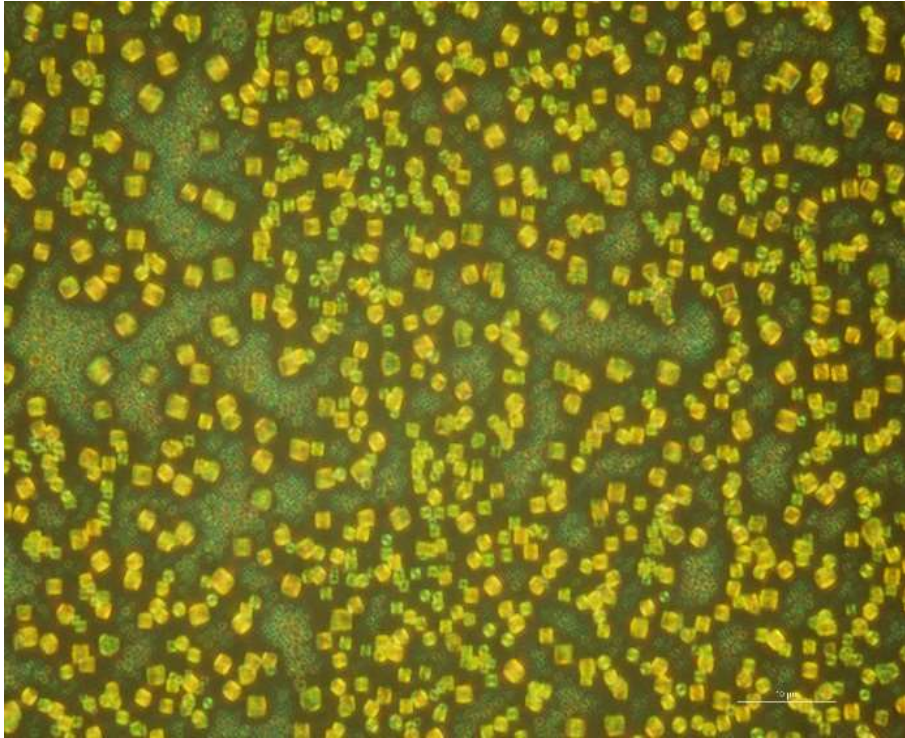
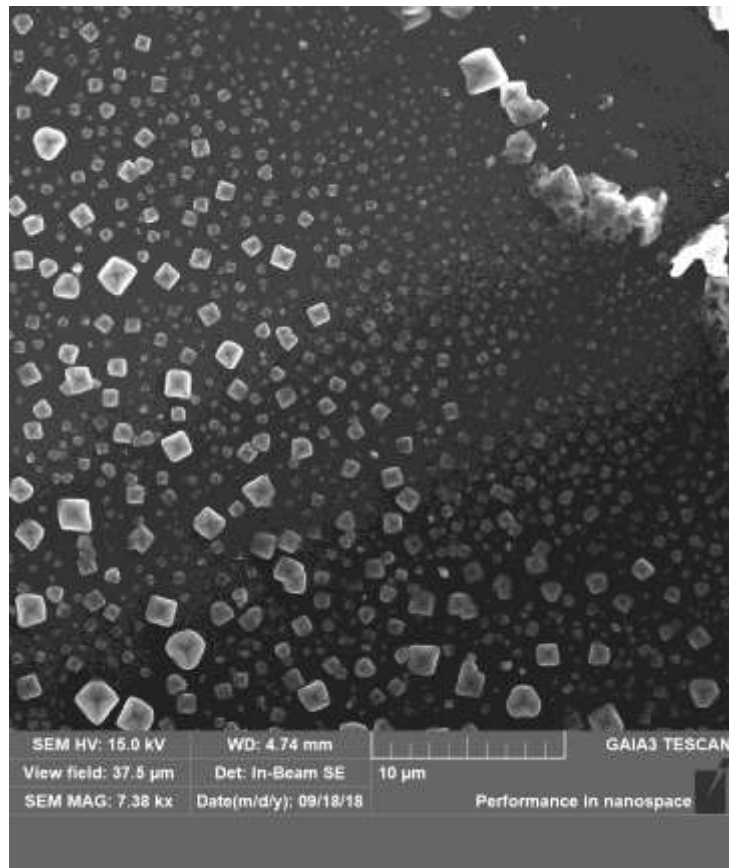


Figure 2.5: Synthesis techniques to grow perovskite single crystals: a) Bridgmann method. b) AVC method. [194]

At the optical microscope: spin-coated samples

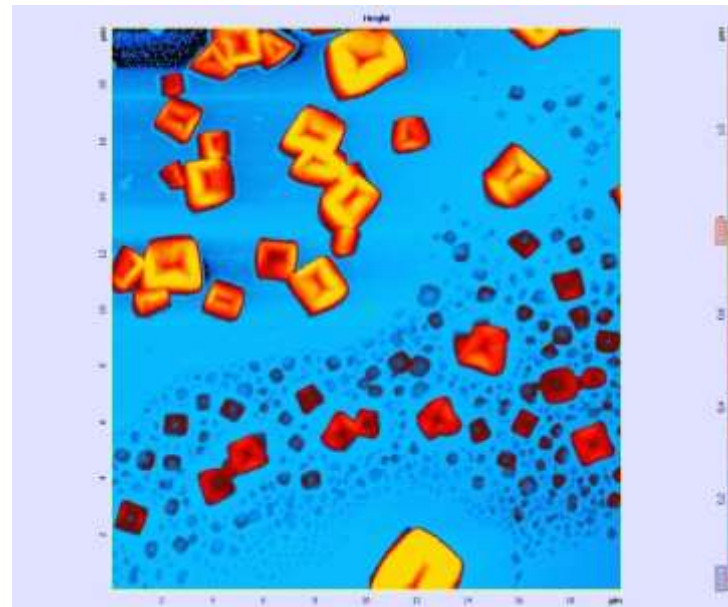


High resolution Imaging SEM



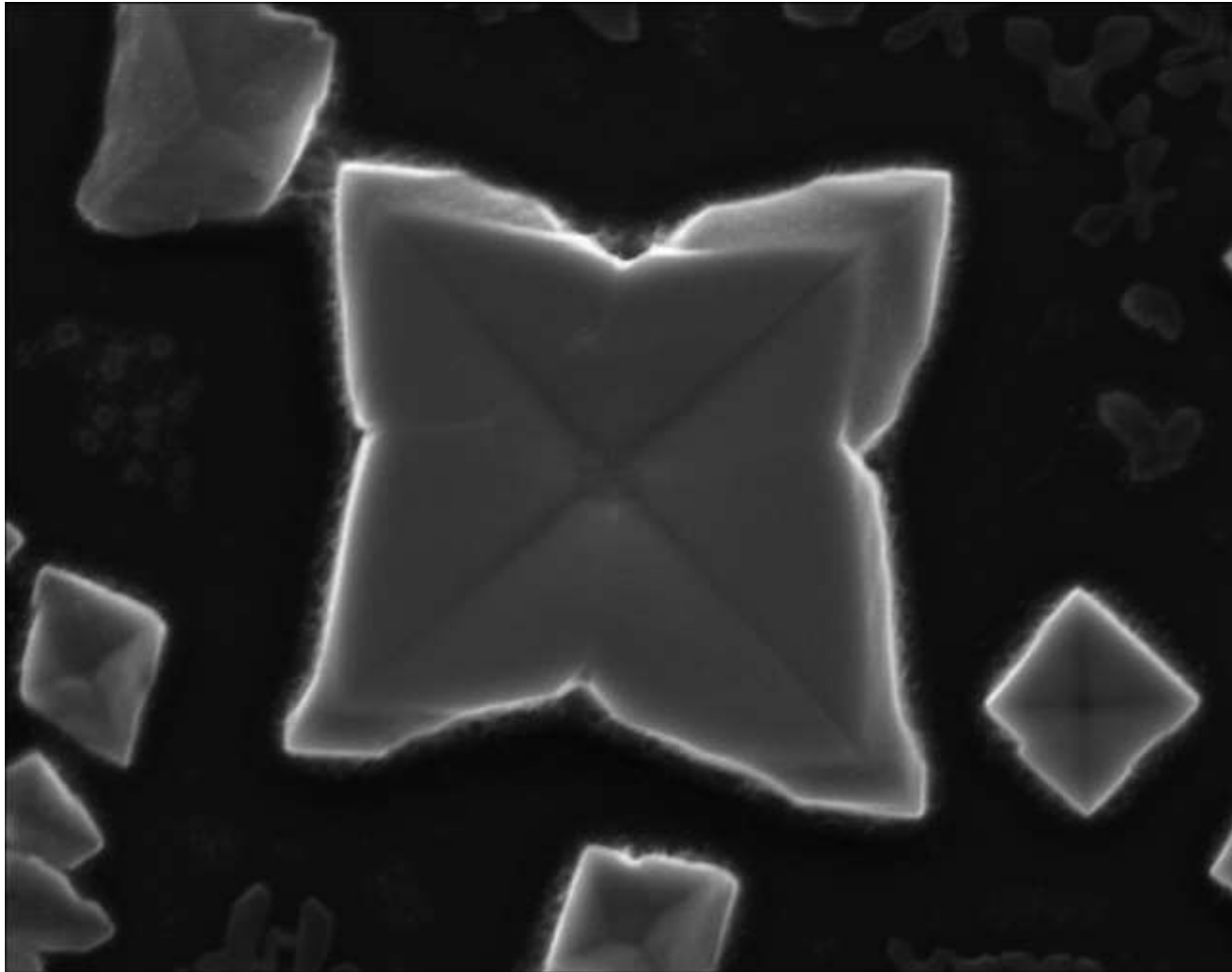
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AFM

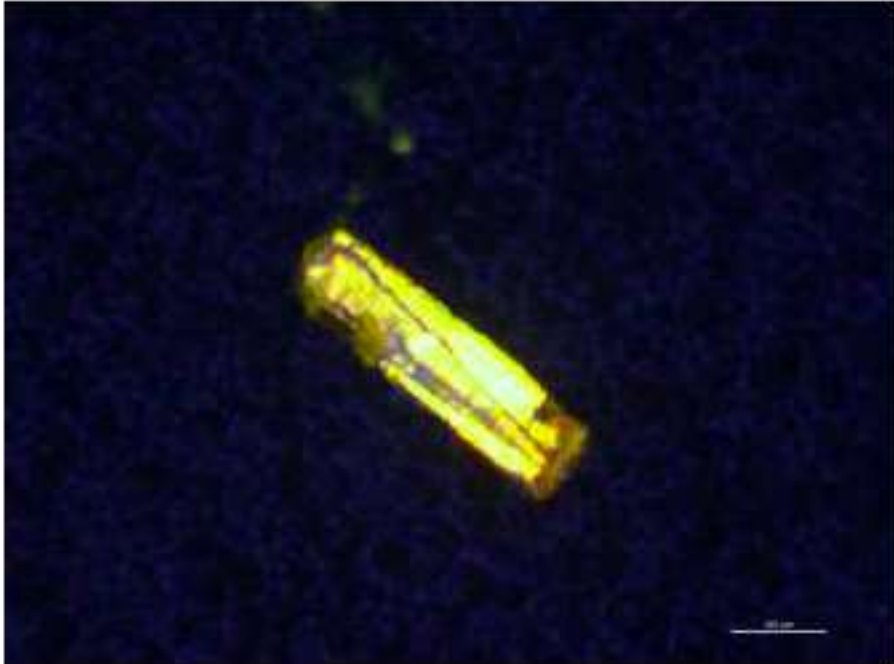


April 15, 2019

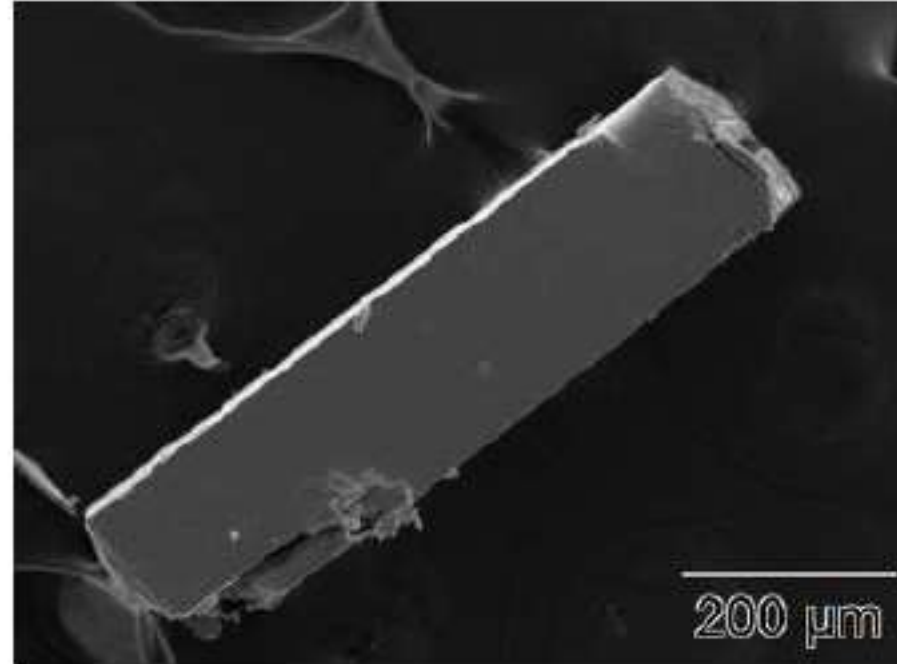
High resolution SEM



Bulk crystals



Using an optical microscope



Using a SEM

What spectroscopy on such samples?

- We need to determine the bandgap: standard cw spectroscopy (transmission/ absorption/ photoluminescence)
- We need to understand the non-radiative recombination paths: temperature-dependent measurements
- We need to understand the carrier interactions and the recombination kinetics: time-resolved experiments, typically at the picosecond time-scale

Moreover: optical spectroscopy at the macro or micro scale?

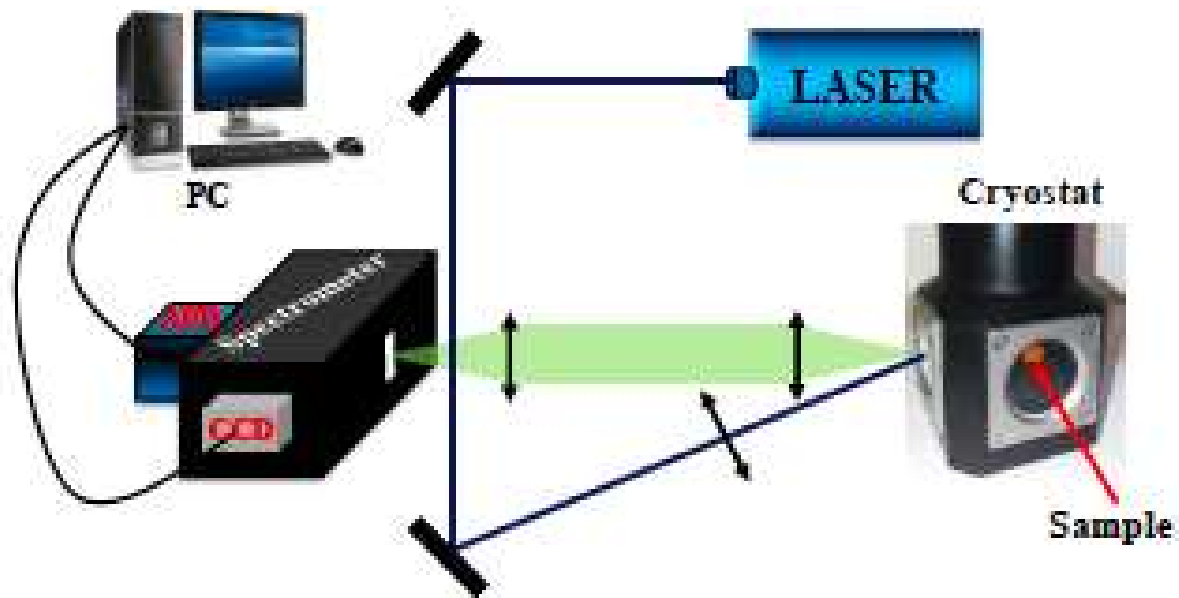
Macro: we probe macroscopic portions of the sample ($\geq 100 \mu\text{m}^2$)

Micro: Spatial resolution at the diffraction limit ($\approx \mu\text{m}$ in the vis)

Near Field detection: spatial resolution limited by the fiber tip ($\approx 100 \text{ nm}$)

Different informations can be extracted!

Here in the labs



MicroPL

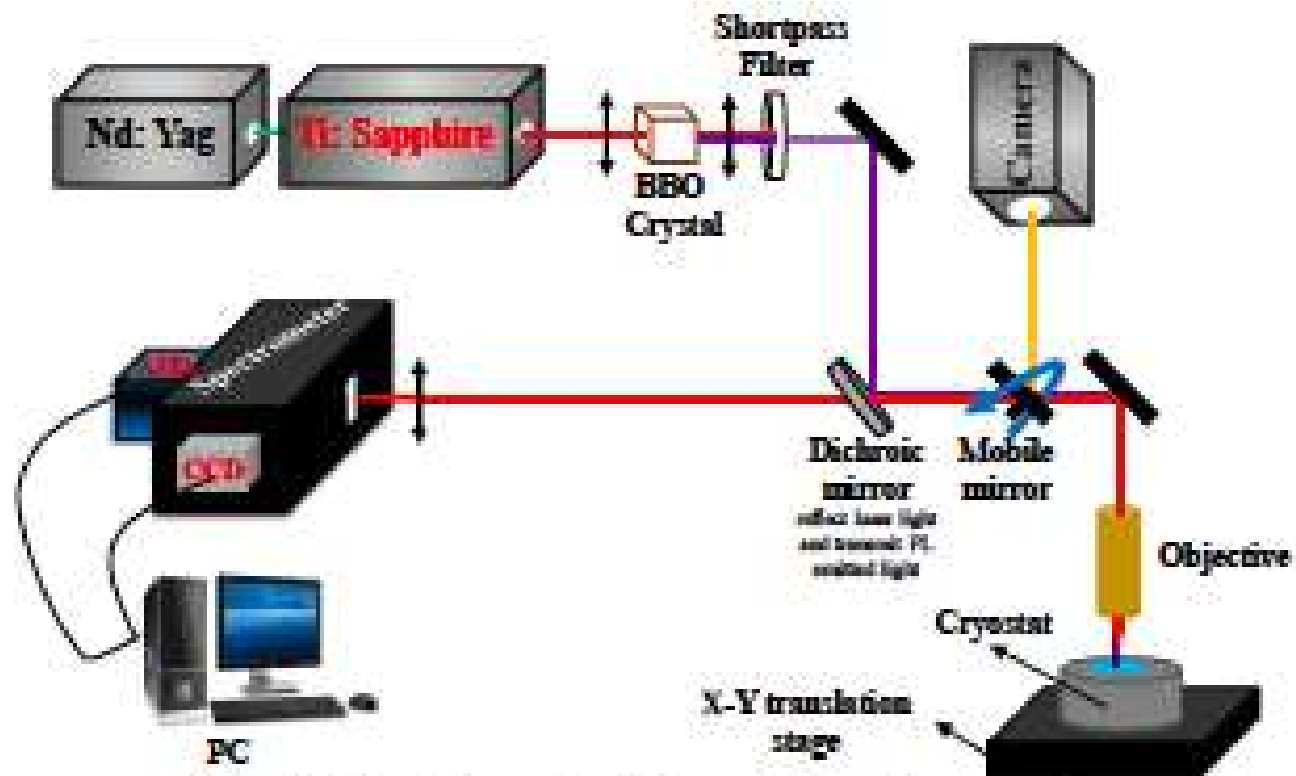
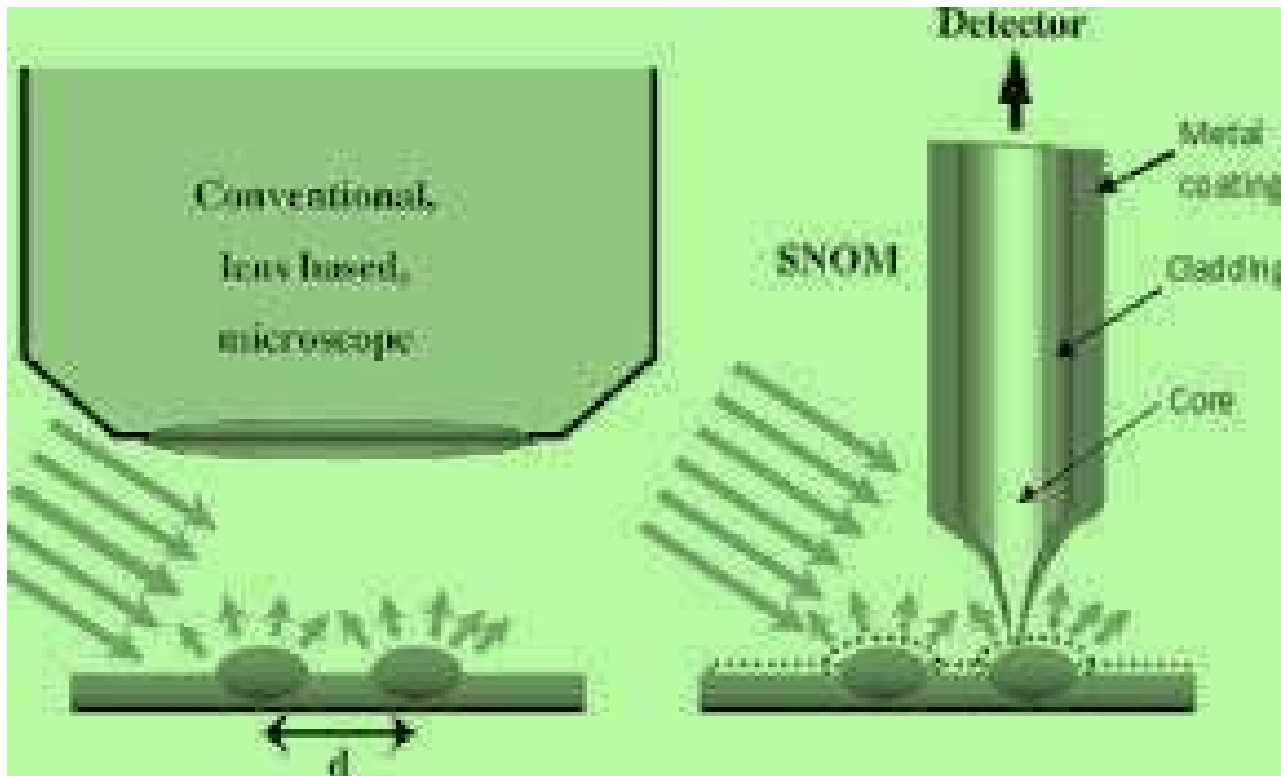
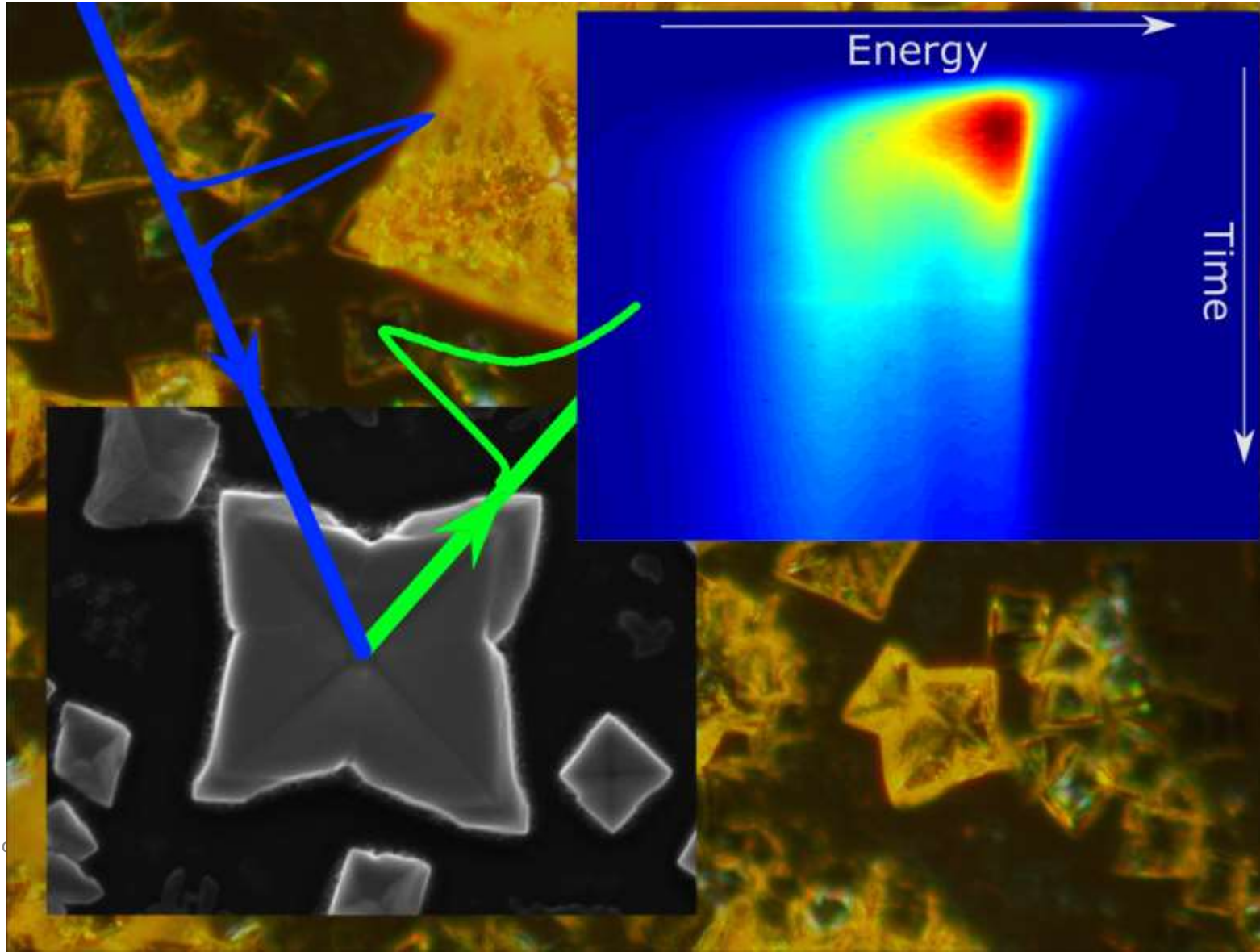


Figure 4.2: Scheme of the experimental setup used for micro-PL measurements.

SNOM

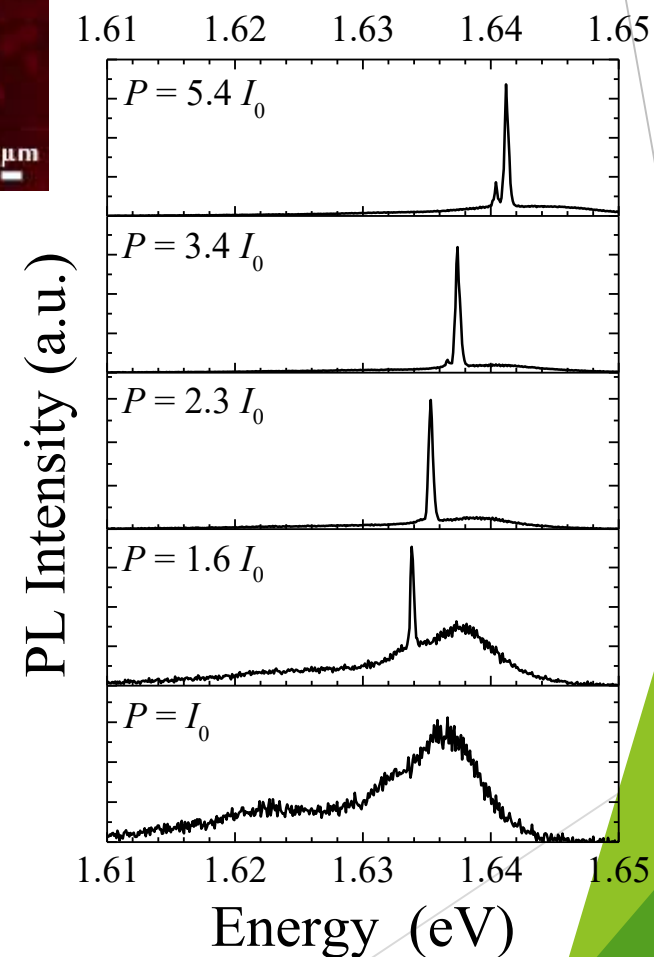
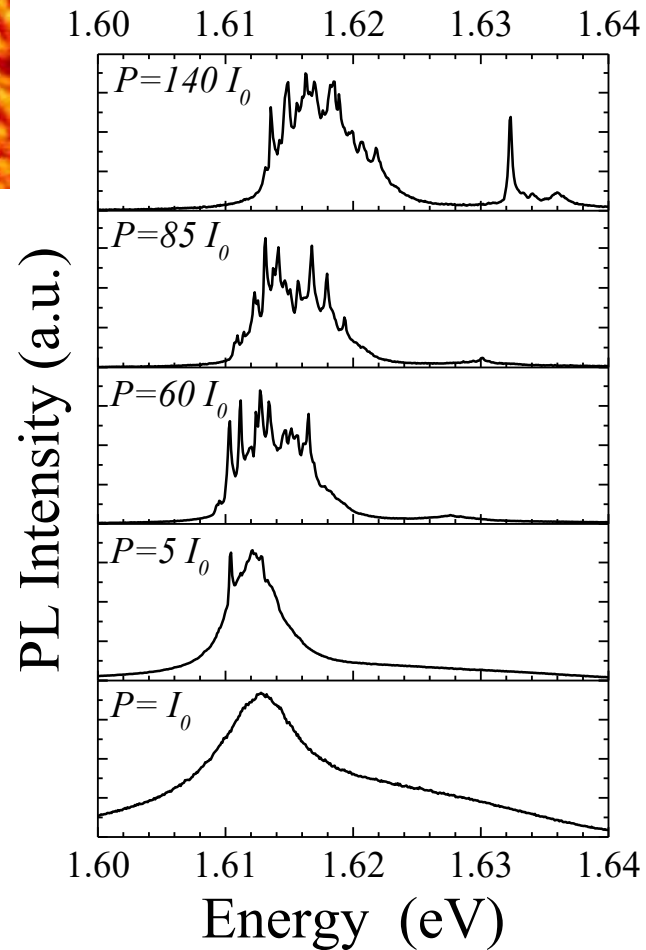
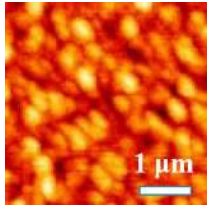


At the end

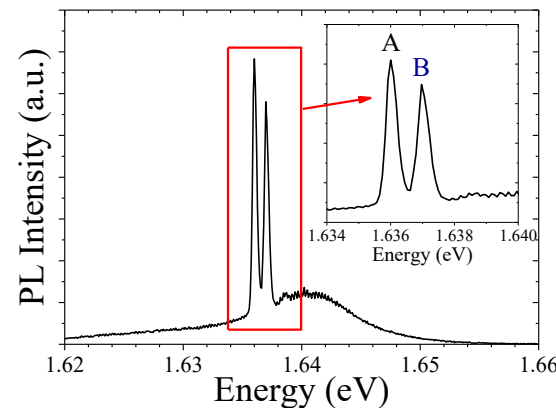
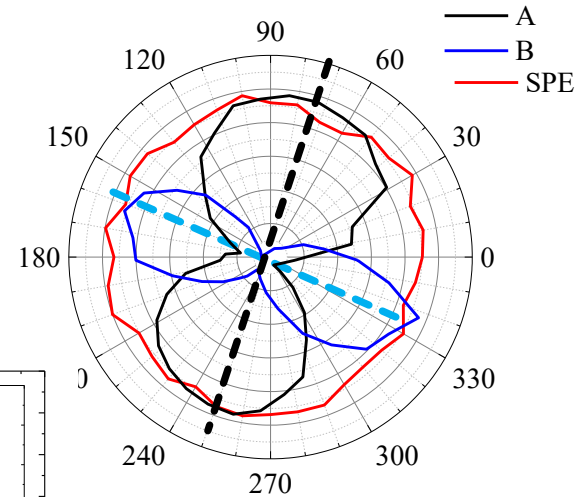
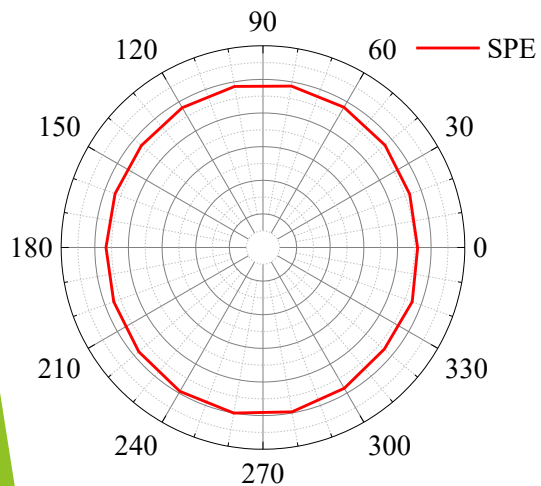
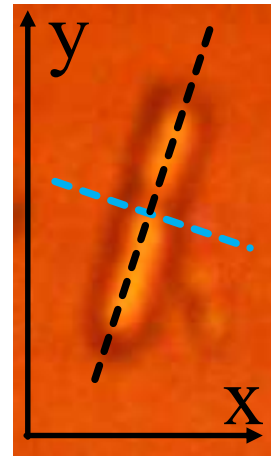
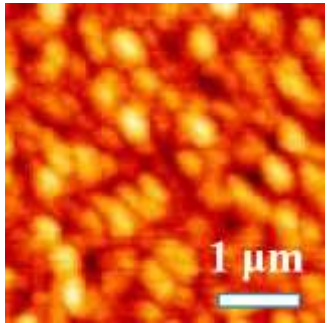
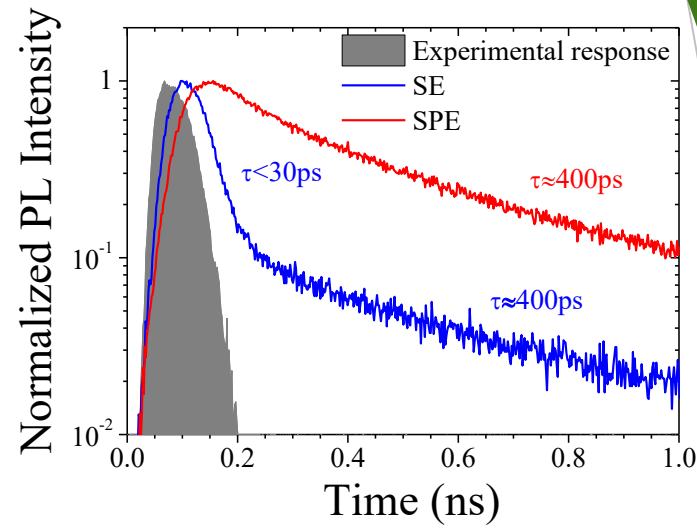


Some examples

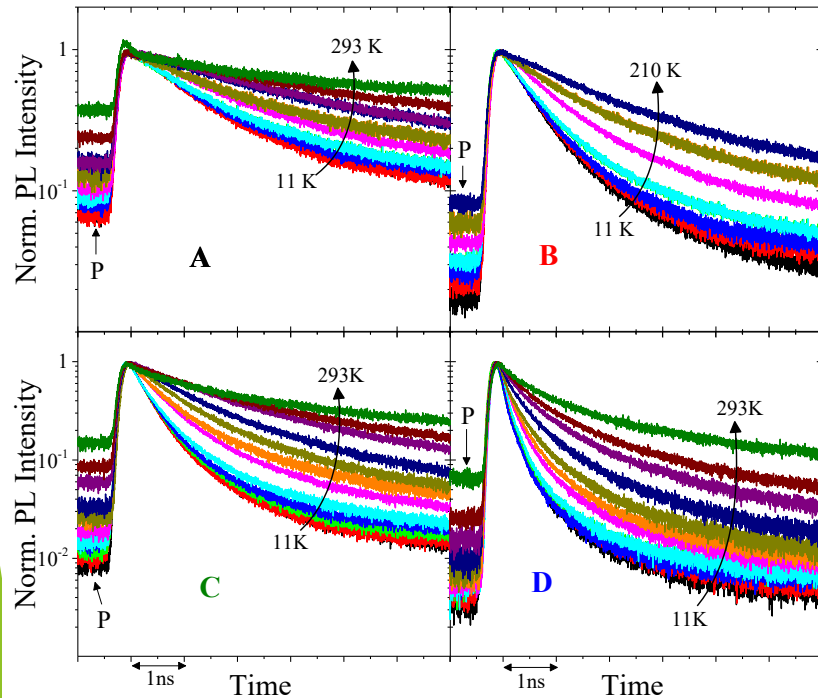
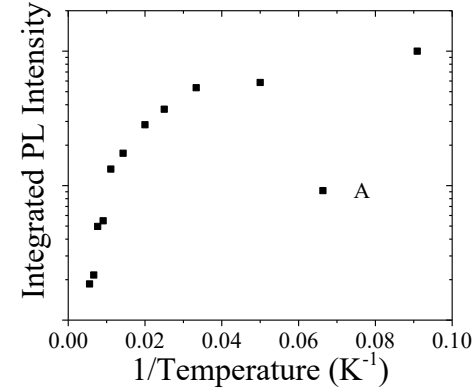
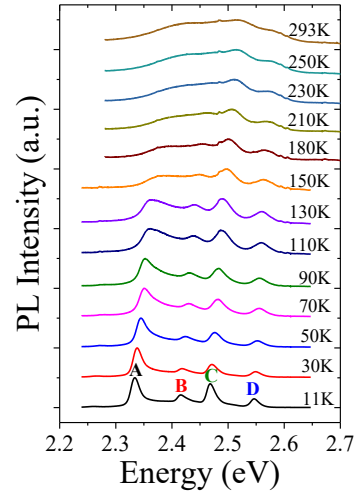
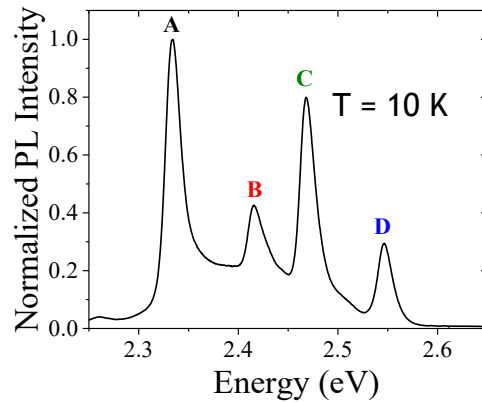
Superlinear emission: ASE or lasing?



Decay kinetics is similar
but polarization
properties are different



Surface states role



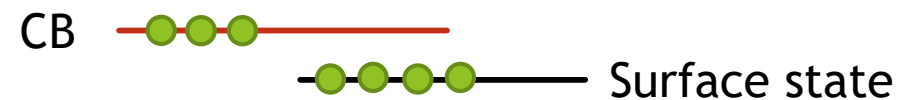
Recombination dynamics slows down increasing the temperature!

The smaller the nanocrystals, the larger the effect

The increase of lifetime with T is counterintuitive ! Usually non radiative channels are more effective as T increases
But....

Large crystals or high temperature (smaller barrier, less surface defects)

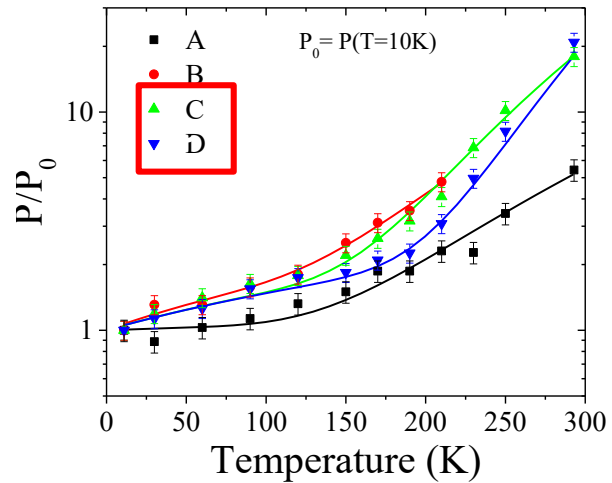
Small crystals or low temperature (larger barrier, more surface defects)



Surface states act as a reservoir and can release population as T increases

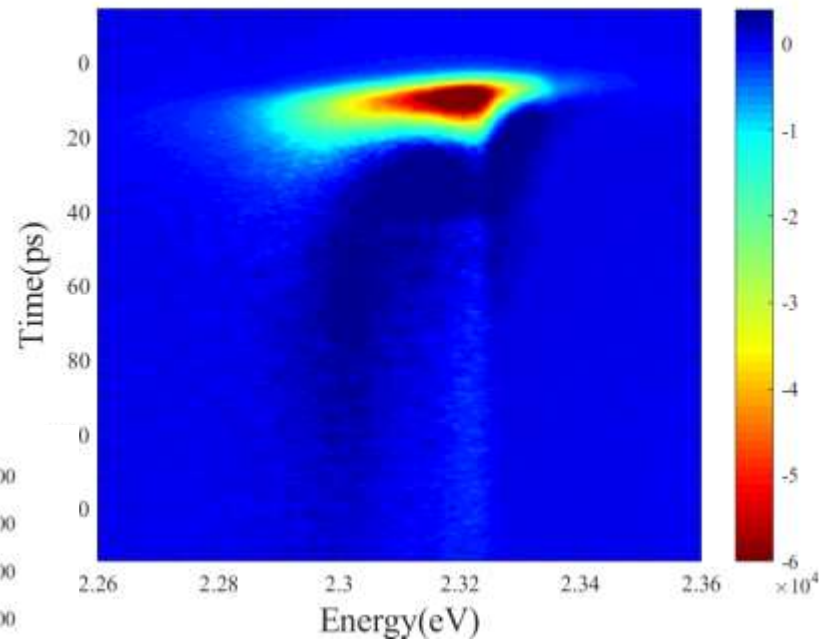
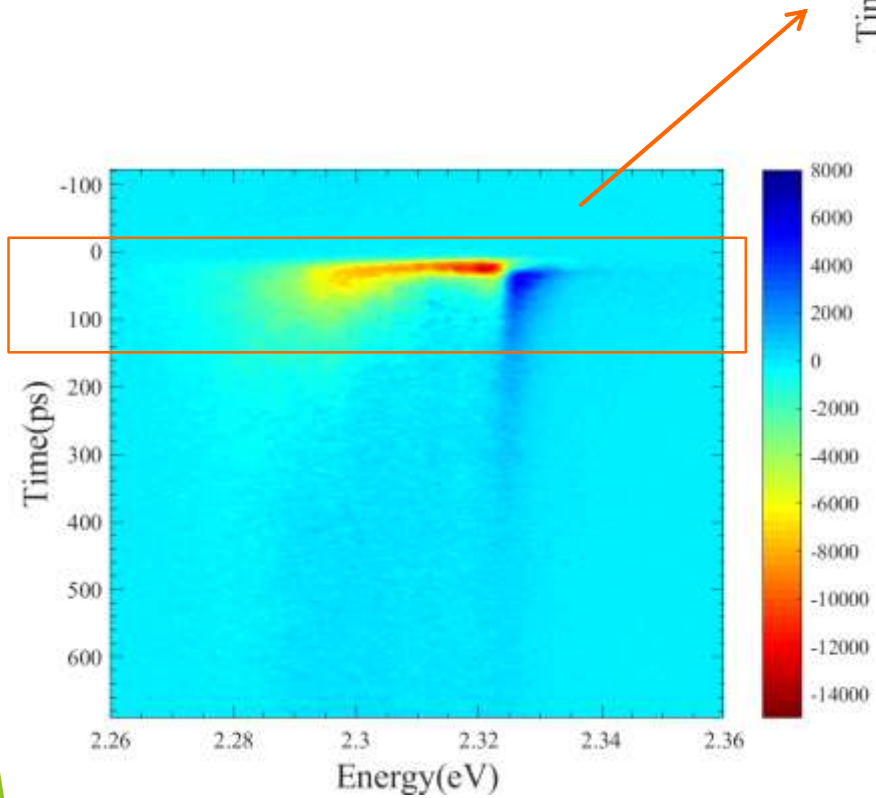
Thermally activated transfer

$$P(T) = AT + Be^{-\frac{E_B}{k_B T}}$$



Band	A (K ⁻¹)	B (10 ⁻³ K ⁻²)	E _B (meV)
A	≈ 10 ⁻³	0.18	33
B		0.48	39
C		2.6	67
D		25	130

Non-linearities with two beams

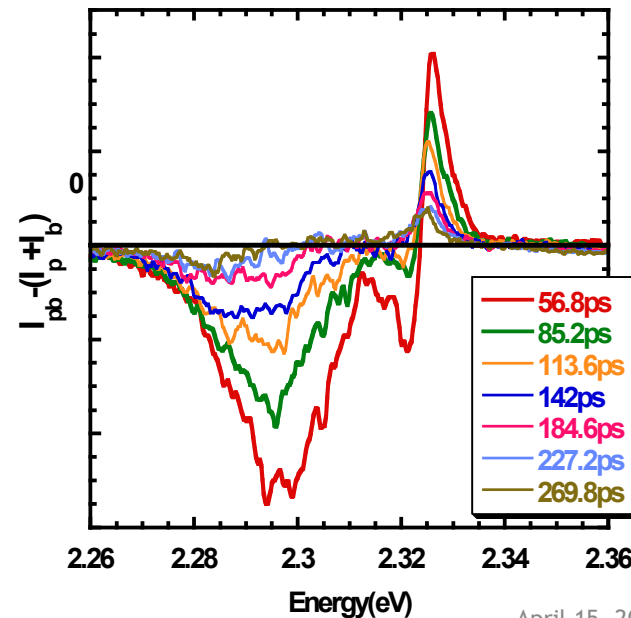
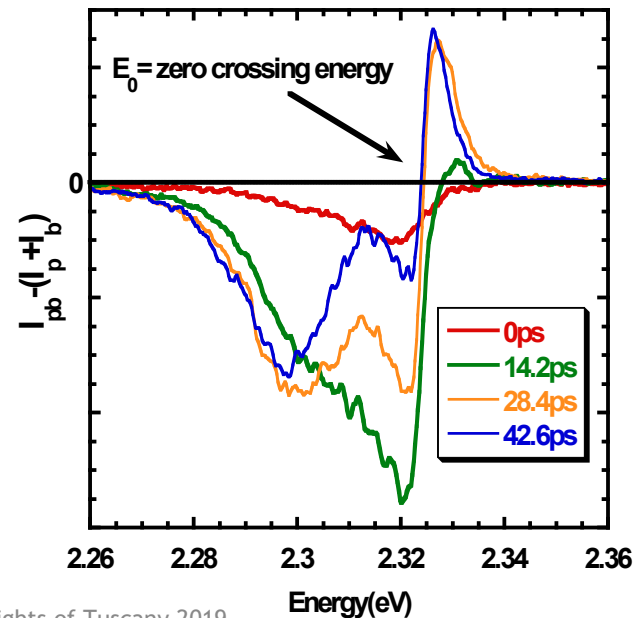


Non resonant bias CW @ 405
nm + ps pulse @ 370 nm
 $I_{pb} - (I_p + I_b)$ vs time

nanop2018-Rome October 1-3

Negative signal: bleaching related to localized/bound states

Positive signal: Superlinearity from excitons formation



Conclusions

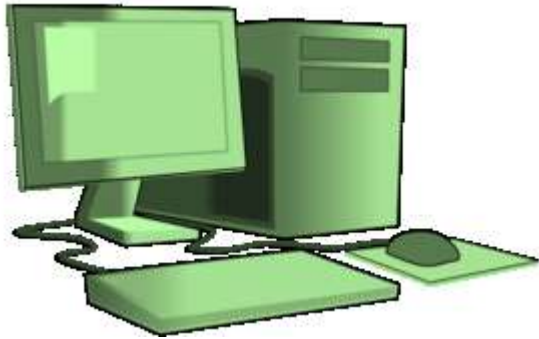
Optical spectroscopy implemented in several different configurations allows to provide a dramatic amount of physical information which is fundamental for the progress of material science.

New classes of artificial-made materials recently realized are of relevance for opto devices: in these years perovskites are probably the most investigated !

A look to the future

- ▶ Controlled deposition of nanocrystals and homogeneous film
- ▶ Definition of post-growth treatment for defect annealing
- ▶ Coupling of perovskites to photonic structures to tailor the light properties
- ▶ Optimization of electrical injection for realization of Leds and Lasers
- ▶ Eco-friendly materials (no lead, etc)

Let's try to think our lives without semiconductors: just 3 objects



Could you survive?

Thanks